

Device Modeling Report

COMPONENTS:
DIODE/ GENERAL PURPOSE RECTIFIER/ PROFESSIONAL
PART NUMBER: CLH02
MANUFACTURER: TOSHIBA



Bee Technologies Inc.

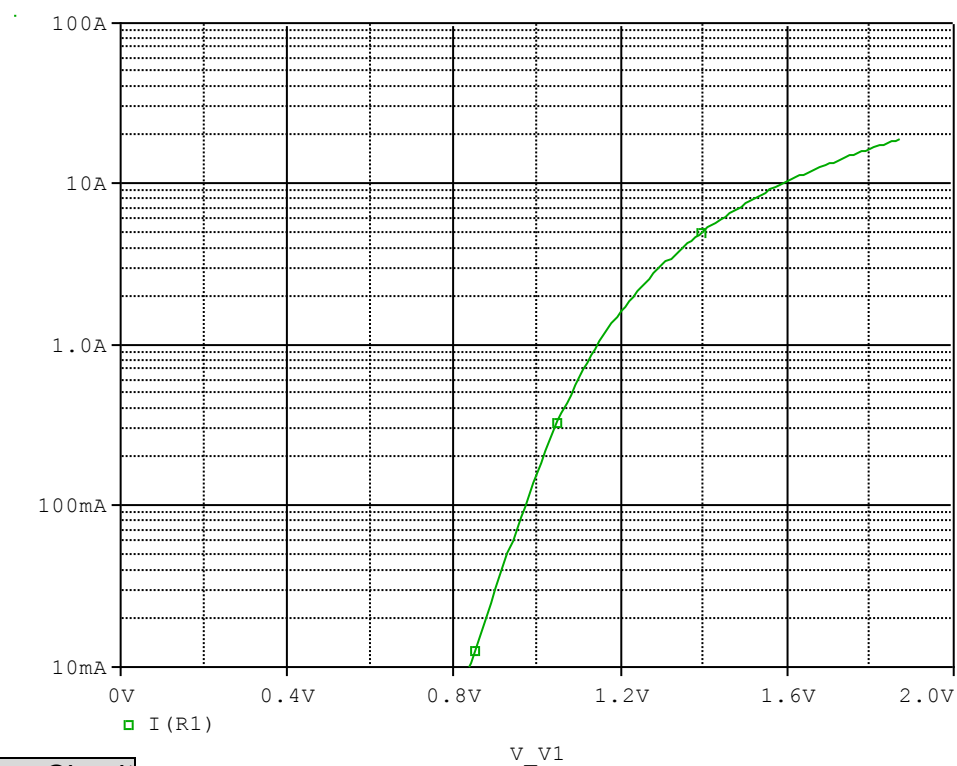
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DIODE MODEL PARAMETERS

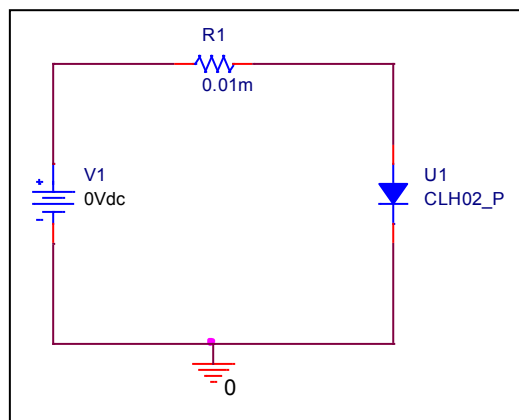
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

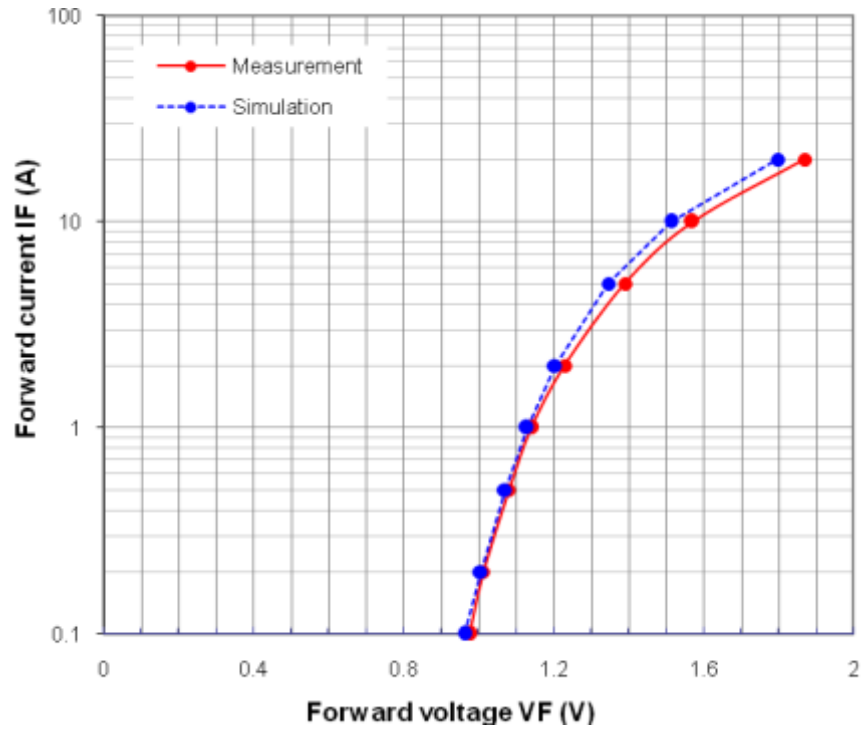


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

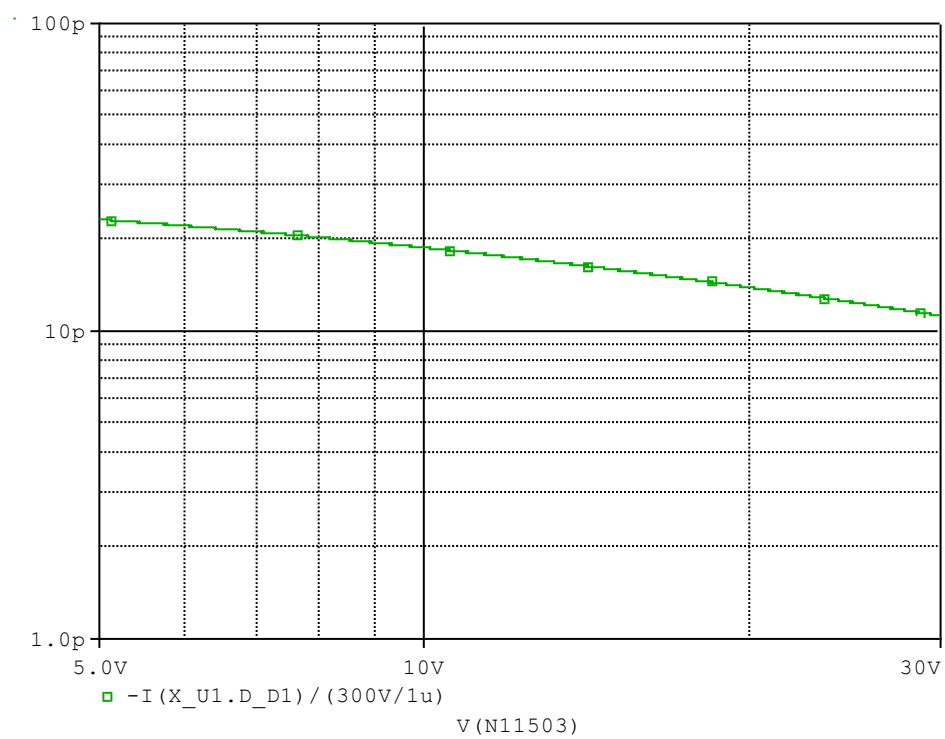


Simulation Result

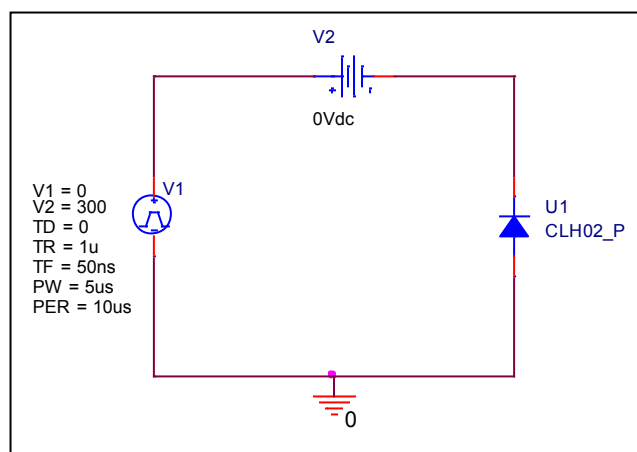
Ifwd (A)	Vfwd (V)		%Error
	Measurement	Simulation	
0.1	0.976	0.963	-1.29
0.2	1.012	1.006	-0.56
0.5	1.080	1.070	-0.90
1	1.140	1.129	-0.93
2	1.230	1.205	-2.07
5	1.390	1.346	-3.17
10	1.570	1.515	-3.53
20	1.87	1.7976	-3.87

Capacitance Characteristic

Circuit Simulation Result

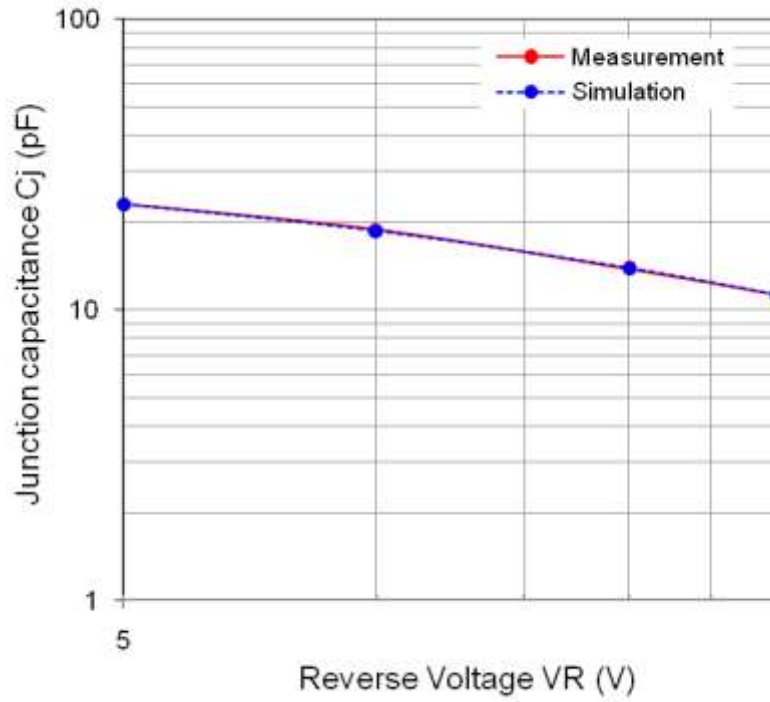


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

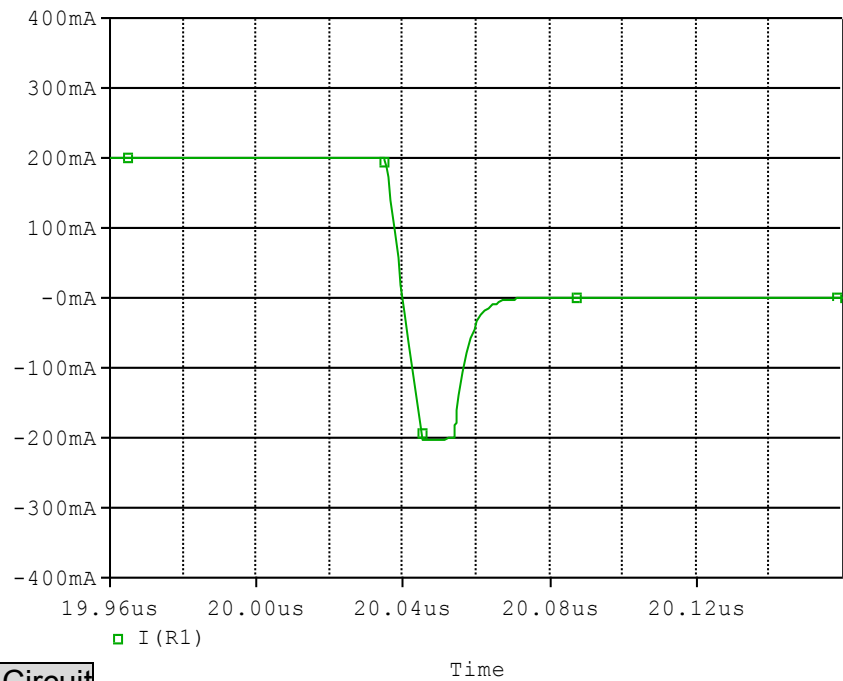


Simulation Result

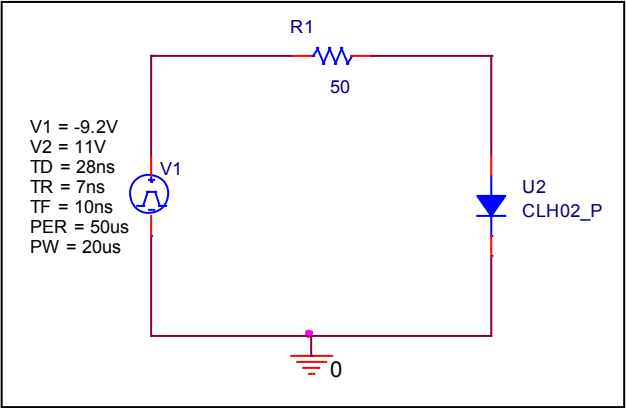
Vrev (V)	Cj (pF)		%Error
	Measurement	Simulation	
5	23.000	23.083	0.36
10	18.800	18.662	-0.73
20	13.800	13.856	0.41
30	11.200	11.213	0.12

Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

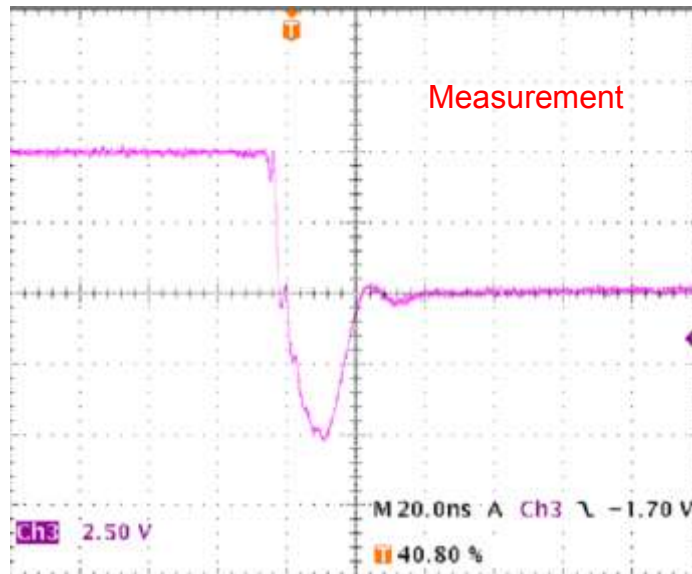


Compare Measurement vs. Simulation

		Measurement	Simulation	%Error
Trj	ns	12.00	11.85	-1.29
Trb	ns	9.60	9.65	0.47
Trr	ns	21.60	21.49	-0.51

Reverse Recovery Characteristic

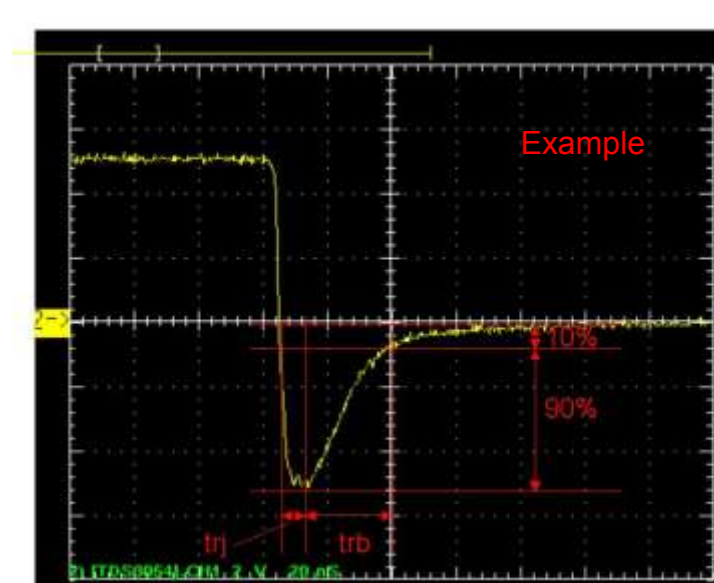
Reference



$T_{rj} = 12.00(\text{ns})$

$T_{rb} = 9.60(\text{ns})$

Conditions: $I_{fwd}=0.2\text{A}$, $I_{rev}=0.2\text{A}$, $R_I=50$



Relation between t_{rj} and t_{rb}